

Alma Mater Studiorum Università di Bologna
Archivio istituzionale della ricerca

Charge carrier dynamics and visible light photocatalysis in vanadium-doped TiO₂ nanoparticles

This is the final peer-reviewed author's accepted manuscript (postprint) of the following publication:

Published Version:

Rossi, G., Pasquini, L., Catone, D., Piccioni, A., Patelli, N., Paladini, A., et al. (2018). Charge carrier dynamics and visible light photocatalysis in vanadium-doped TiO₂ nanoparticles. APPLIED CATALYSIS. B, ENVIRONMENTAL, 237, 603-612 [10.1016/j.apcatb.2018.06.011].

Availability:

This version is available at: <https://hdl.handle.net/11585/641782> since: 2018-10-03

Published:

DOI: <http://doi.org/10.1016/j.apcatb.2018.06.011>

Terms of use:

Some rights reserved. The terms and conditions for the reuse of this version of the manuscript are specified in the publishing policy. For all terms of use and more information see the publisher's website.

This item was downloaded from IRIS Università di Bologna (<https://cris.unibo.it/>).
When citing, please refer to the published version.

(Article begins on next page)

This is the final peer-reviewed accepted manuscript of:

G. Rossi, L. Pasquini, D. Catone, A. Piccioni, N. Patelli, A. Paladini, S. Caramori, A. Molinari, P. O'Keeffe, and F. Boscherini, Charge carrier dynamics and visible light photocatalysis in vanadium-doped TiO₂ nanoparticles, *Applied Catalysis B: Environmental* 237, 603 – 612 (2018). DOI: 10.1016/j.apcatb.2018.06.011.

The final published version is available online at:

<http://dx.doi.org/10.1016%2Fj.apcatb.2018.06.011>

© 2018. This manuscript version is made available under the Creative Commons Attribution-NonCommercial-NoDerivs (CC BY-NC-ND) License 4.0 International (<http://creativecommons.org/licenses/by-nc-nd/4.0/>)

Charge carrier dynamics and visible light photocatalysis in vanadium-doped TiO₂ nanoparticles

Giacomo Rossi,¹ Luca Pasquini,^{1,§} Daniele Catone,² Alberto Piccioni,¹ Nicola Patelli,¹ Alessandra Paladini,³
Alessandra Molinari,⁴ Stefano Caramori,⁴ Patrick O' Keeffe,³ Federico Boscherini¹

1 - Department of Physics and Astronomy, Alma Mater Studiorum Università di Bologna, V. C. Berti-Pichat 6/2, 40127 Bologna, Italy

2 - CNR-ISM, Division of Ultrafast Processes in Materials (FLASHit), Area della Ricerca di Roma Tor Vergata, Via del Fosso del Cavaliere 100, Rome, Italy

3 - CNR-ISM, Division of Ultrafast Processes in Materials (FLASHit), Area della Ricerca di Roma 1, Monterotondo Scalo, Italy

4 - Department of Chemical and Pharmaceutical Sciences, University of Ferrara, Via Luigi Borsari 46, 44121 Ferrara, Italy

§ corresponding author: luca.pasquini@unibo.it

Abstract: Vanadium-doped TiO₂ nanoparticles (V-TiO₂ NPs) with a V/Ti ratio of 3.0 at. % were prepared by gas-phase condensation and subsequent oxidation at elevated temperature. Both photocatalytic activity for -NO₂ reduction and photoelectrochemical water splitting were induced by V-doping in the visible spectral range $\lambda > 450$ nm, where undoped TiO₂ NPs are completely inactive. The photocatalytic properties were correlated with the ultrafast dynamics of the photoexcited charge carriers studied by femtosecond transient absorption (TA) spectroscopy with three different excitation wavelengths, i.e. $\lambda_e = 330, 400$, and 530 nm. Only in V-doped NPs, the photoexcitation of electrons into the conduction band by sub-bandgap irradiation ($\lambda_e = 530$ nm) was detected by TA spectroscopy. This observation was associated with electronic transitions from an intra-gap level localized on V⁴⁺ cations. The photoexcited electrons subsequently relaxed, with characteristic times of 200-500 ps depending on λ_e , into Ti-related surface traps that possessed suitable energy to promote -NO₂ reduction. The photoexcited holes migrated to long-lived surface traps with sufficient overpotential for the oxidization of both 2-propanol and water. On the basis of TA spectroscopy and photocurrent measurements, the position of the dopant-induced intra-gap level was estimated as 2.2 eV below the conduction band minimum.

Keywords: Photocatalysis; TiO₂; transient absorption spectroscopy; NO₂ reduction; vanadium doping.

1. Introduction

TiO₂ is one of the most studied wide band gap oxide semiconductors due to its photocatalytic properties, opening the way to various applications such as hydrogen production from water and environmental cleaning (air and water) [1–5]. However, because of its wide band gap (3.0 eV for rutile and 3.2 eV for anatase [4]), only a small fraction of the solar spectrum, i.e. UV light (3–5% of total), can be used for photocatalytic processes.

A widely investigated strategy to shift the optical absorption of TiO₂ towards the visible region is doping with ionic species [6]. However, the enhanced optical absorption does not always correspond to a photocatalytic activity in a previously inactive spectral range. In fact, absorption from intra-gap states may not generate sufficiently strong oxidants for the desired reaction. This means that the absorption spectrum of a photocatalyst does not necessarily match its photocatalytic activity spectrum. A clear mechanistic view of the dopant role in photocatalysis is far from being established. The dopants in TiO₂ can be classified into: 1) nonmetal dopants (C, N, F, S) [7–9] and 2) metal dopants, especially 3d transition metals and noble metals (Pt, Cu) [10–12]. Metal dopants can influence TiO₂ photocatalysis by three principal mechanisms: i) improvement of the electron-hole separation (beneficial) by selective trapping, usually at low doping concentration (< 1 at.%) [6,13]; ii) reduction of carriers lifetime (detrimental) due to the dopant that acts as a recombination center [2,14], and iii) enhancement of optical absorption in the visible range.

The first two mechanisms are not expected to modify the spectral range of photoactivity. In this work, we address in particular the third mechanism and aim at achieving both optical absorption and photocatalytic activity in a visible spectral range ($\lambda > 450$ nm) where pure TiO_2 is completely inactive. We investigate undoped TiO_2 nanoparticles (NPs) and vanadium-doped TiO_2 (V- TiO_2) NPs. V-doping is known to induce an absorption red-shift and has been reported to improve the photocatalytic degradation of water pollutants under solar irradiation [15–19]. Several studies have shown that V induces electronic states within the band gap of TiO_2 . Umebayashi et al. [20] found by *ab-initio* calculations that V generates a narrow band of partially filled levels about 0.7 eV below the conduction band minimum (CBM) of TiO_2 . This estimate was confirmed by Patel et al. [16], whereas Osorio-Guillén et al. calculated a deeper level at 1.36 eV below the CBM [21]. At present, it is not clear whether the photocatalytic activity extends into a spectral region inaccessible to pure TiO_2 . Answering this question is one of the purposes of the present paper.

Time-resolved pump-probe optical spectroscopy is a key tool to elucidate the charge carrier dynamics that underlie photocatalysis. Several investigations were performed on undoped TiO_2 using ultrabandgap excitation ($\lambda_e \approx 330 - 360$ nm) [22–32]. Photoexcitation leads to the almost instantaneous formation of free charge carriers, some of which are rapidly trapped near surface sites. The spectroscopic signature of free and trapped carriers has been studied by transient absorption (TA) spectroscopy by Yoshihara et al. [26] who showed that the response is composed of three positive features ascribed to trapped holes (TH), trapped electrons (TE) and free electrons in the conduction band (FE). From an atomistic point of view, hole trapping is due to the formation of O^- or O_3^- according to $\text{O}^{2-} + \text{h}^+ \rightarrow \text{O}^-$ or $\text{O}^{2-} + \text{O}_2 + \text{h}^+ \rightarrow \text{O}_3^-$ [32–34], while electron trapping is due to the $\text{Ti}^{4+} + \text{e}^- \rightarrow \text{Ti}^{3+}$ process [35]. The rise time of signals related to the three mentioned components allows to explore the trapping dynamics of the respective charge carriers. The trapping time constants associated with the electron signals reported in the literature are relatively similar: ~ 180 fs according to Skinner et al. [36], ~ 260 fs (Yang and Tamai [27]) and ~ 170 fs (Tamaki et al. [28]). However, since the TE and FE signals are superimposed, it is not clear how to associate these times to the different physical processes. There is less consensus on the hole trapping times: Yang and Tamai quote a value < 50 fs while Tamaki et al. estimate it to be ~ 220 fs. After their initial formation, the trapped and free carriers decay by various processes on the timescale of 10 – 100s of ps or more, depending on the carrier density and the specific system investigated. The time decay of the spectral features is related to the dynamics of the charge carriers.

Ultrafast spectroscopy was also applied to track photoexcited charge carriers in doped TiO_2 [37–42]. Ikeda et al observed a second-order kinetics due to electron-hole recombination, the rate constant of which increases with increasing dopant concentration [42]. Similarly, in $\text{TiO}_2 - \text{M} - \text{TiO}_2$ multilayer films (M = Co or W) Sun et al. [37] showed that doping does not change the wavelength dependence of the TA spectra but that it induces a faster decay of the spectral features.

Studies of the local structure of V dopants in TiO_2 provide the essential prerequisite for an understanding of the optical properties and of the charge carrier dynamics. We have recently published X-ray Absorption Fine Structure (XAFS) studies which demonstrate that V always occupies a substitutional site in V- TiO_2 NPs [43] and in V- TiO_2 thin films [44] irrespective of whether they have mainly anatase or rutile structure. By exploiting the chemical sensitivity of XAFS, we have also performed a differential illumination High Energy Resolution Fluorescence Detected (HERFD) – X-ray Absorption Near Edge Structure (XANES) experiment on V- TiO_2 NPs [45]. This experiment demonstrated that visible light ($\lambda = 532$ nm) absorption is mainly due to electron transfer from V dopant sites to Ti defective ones. By means of a quantitative analysis, a long electron lifetime in the defective sites of ~ 0.8 ms was estimated. This work followed our previous study of plasmon-induced hot electron transfer in Au- TiO_2 nanostructures [46]. In the context of X-ray spectroscopic investigations we note that electron transfer to defective Ti sites in undoped or dye-sensitized TiO_2 NPs has been demonstrated by time resolved methods on the 100 ps time scale by Rittmann Frank et al. [47] and more recently on the 100 fs time scale by Obara et al. [48].

In this paper, we employ TA spectroscopy with sub 100 fs time resolution to study electron and hole dynamics after photoexcitation at three different wavelengths ($\lambda_e = 330, 400, 530$ nm). We correlate the peculiar TA features of undoped and V-doped TiO₂ NPs to their photoactivity at different excitation wavelengths. We will show that V-doped TiO₂ NPs exhibit a clear photoactivity, both for nitro group reduction and for photoelectrochemical water splitting, in the visible spectral range ($\lambda > 450$ nm) where undoped TiO₂ is completely inactive.

2. Experimental

TiO₂ and V-TiO₂ NPs were grown via gas phase condensation. The evaporation material was either pure Ti in powder form or a Ti-V powder mixture. Thermal evaporation was carried out in a ultra-high vacuum chamber filled with 266 Pa of He. The NPs, which nucleated by condensation of the supersaturated metal vapors, were collected via thermophoresis on a rotating steel cylinder cooled by liquid nitrogen. After the evaporation, pure O₂ was admitted into the chamber up to a final pressure of 2.6 kPa, yielding oxidized dark-gray NPs with an amorphous structure. After annealing at 400 °C in air for 6 hours, the undoped NPs turned white, while the V-doped NPs appeared yellowish. X-ray powder diffraction (XRD) and transmission electron microscopy (TEM) showed that complete crystallization took place [45]. The X-ray powder diffraction patterns (Figure S1 of the supplemental material) indicated that TiO₂ and V-TiO₂ NPs had a similar phase composition with about 75 wt% rutile, 15 wt% anatase, and 5 wt% brookite. These TiO₂ polymorphs were finely mixed at the nanoscale level as shown by high-resolution TEM [45]. The average size of the NPs was 12 ± 1 nm according to TEM analysis. The V/Ti ratio estimated by energy dispersive X-ray spectroscopy in a scanning electron microscope was 3.0 ± 0.5 at. %. Further information about the deposition procedure can be found in previous publications [43,45].

Diffuse reflectance (DR) spectra were collected by a Perkin Elmer Lambda 45 double beam spectrophotometer equipped with an RSA-PE-20 integrating accessory (Labsphere). The samples were measured as solid mixtures in a matrix of ground NaCl. Prior to measurement, a blank of pure NaCl was recorded as a reference. The UV-vis absorbance, reported in Figure S2 of the supplementary material, were obtained by applying the Kubelka-Munk function to DR spectra.

In order to prepare suitable samples for the TA measurements, the NPs were suspended in a 70/30 bi-distilled water/acetic acid solution with overall concentration of 1 mg NPs/1 ml solution. The obtained stable suspension was deposited on UV transparent quartz substrates via drop casting. The thickness of the samples was increased until an optical density (OD) of 1.0 at $\lambda = 400$ nm was achieved.

Ultrafast TA spectroscopy measurements in the pump (λ_e) and probe (λ_p) scheme were performed with a laser system consisting of a chirped pulse amplifier seeded by a Ti:Sa oscillator. The pump pulses were produced either by frequency doubling of the 800 nm fundamental (400 nm) or by using the output of an optical parametric amplifier (330 and 530 nm). The white light probe (350 - 800 nm), on the other hand, was generated in a commercial TA spectrometer (FemtoFrame II, IB Photonics) employing a split beam configuration in which 50 % of the white light passes through the sample while the remainder is used as a reference to account for pulse to pulse fluctuations in the white light generation. The pump pulse is loosely focused (circular spot of diameter = 500 μ m) onto the sample with an energy density from 350 μ J/cm² to 7 mJ/cm²; unless otherwise noted the energy density employed was 1.8 mJ/cm². The spot diameter of the probe pulse is much smaller (approx. 150 μ m) and its delay time with respect to the pump pulse is scanned in time by varying the length of its optical path. The instrument response function was measured to be approximately 80 fs. All measurements were performed in air at room temperature. Further details of the set-up can be found in previous publications [49,50].

The photocatalytic activity of the NPs exposed to visible light irradiation was tested by monitoring the reduction of the NO₂ group in 4- nitrobenzaldehyde (NO₂-C₆H₄-CHO). To this purpose, a fixed amount (10 mg) of NPs was suspended in 3 mL of a 9×10^{-5} M solution of NO₂-C₆H₄-CHO in a CH₃CN/C₃H₈O (4/1) mixture. The suspension was degassed by bubbling N₂ for 20 minutes. Afterwards it was irradiated by a LOT-Oriel solar

simulator, equipped with both an AM1.5G filter and a cut-off filter $\lambda > 450$ nm. At desired time intervals, the irradiation was stopped and after centrifugation the absorbance values of the liquid phase at 264 nm and at 312 nm were recorded by a Jasco V570 spectrophotometer. Control experiments were carried out keeping the samples in the dark for the required period. Moreover, a solution (3 mL) of a $\text{CH}_3\text{CN}/\text{C}_3\text{H}_8\text{O}$ (4/1) mixture containing $\text{NO}_2\text{-C}_6\text{H}_4\text{-CHO}$ (9×10^{-5} M) was irradiated in the absence of photocatalyst.

Incident photon-to-current conversion efficiency (IPCE) spectra were measured in KOH (0.1 M, pH=13) under a bias potential of 0.5 V vs saturated calomel electrode (SCE). For the realization of the photoanodes, 10 mg of NPs were dispersed in 0.2 ml of a 1/1 distilled water/acetylacetone solution. The resulting paste was uniformly distributed by sliding a glass rod onto a glass substrate coated by a 100 nm thick layer of indium tin oxide (ITO glass). The ITO sheet resistance was 20 Ω/square . The ITO glass was previously treated with an acidic solution to make its surface more hydrophilic and to avoid the presence of areas uncoated by the NPs. Finally, the photoanodes were annealed at 400°C in air for 2 hours. The final thickness of the NPs layer on ITO was 1 μm . The photoanodic current was recorded from 350 to 500 nm with 5 nm steps using a PGSTAT204 electrochemical workstation. The PGSTAT204 output signal, proportional to the photoanodic current, was fed into a lock-in amplifier and the incident light was chopped at 2 Hz. The incident monochromatic irradiance was measured with a calibrated pyroelectric sensor. IPCE was calculated according to: $\text{IPCE}(\%) = 1.24 \cdot 10^3 J_\lambda (\mu\text{A cm}^{-2}) / [\lambda(\text{nm}) \cdot P_\lambda (\text{W m}^{-2})]$, where J_λ and P_λ are the photocurrent density and incident radiant power density at wavelength λ .

3. Results and Discussion

3.1 Transient absorption spectroscopy: ultrabandgap (330 nm) excitation

We start by reporting and discussing measurements performed with ultrabandgap excitation, $\lambda_e = 330$ nm. The TA spectra for undoped and V-doped NPs are reported in Figure 1 as a function of the probe wavelength (λ_p) for selected time delays in the range $t = 0.2 - 250$ ps after the pump pulse. The same data are reported in 2 dimensions as a function of (λ_p, t) in Figure S3 of the supplemental material. The presence of two bands centered at approximately 400 nm and 730 nm is apparent. The two samples have spectral features as a function of λ_p which are similar to each other and to the literature results on undoped TiO_2 [26], implying that V-doping does not significantly alter the state of photoexcited carriers; a significantly better spectral resolution of the present spectra compared to literature results should be pointed out.

As recently reviewed by Schneider et al. [2], several TA studies on TiO_2 invariably assigned TA bands centered at 400-500 nm to trapped holes (TH) on the NPs surface and TA bands centered at 600-800 nm to trapped electrons (TE), also on the NPs surface. A certain spread in the energies of spectral features is present in the literature, and depends on the nature of the sample and its environment. The presence of a monotonically increasing background superposed to these bands was ascribed to intra-band transitions of free electrons (FE) photo-excited in the conduction band [26,28]. On these grounds, we can confidently attribute the band centered at 390-400 nm to the filling of trapped holes (TH), and that centered at about 730 nm to the excitation of TE. The contribution of the background FE signal increases approximately as $\lambda_p^{1.7}$ [26]. A reliable determination and subtraction of the FE signal requires an infrared probe, i.e. $\lambda_p = 1500 - 2500$ nm, which was not available in our set up. Since the separation of TE and FE signals was not possible in the present data set, in the following we will refer to the TA signal between 600 nm and 800 nm as simply due to electrons E ($E = \text{TE} + \text{FE}$).

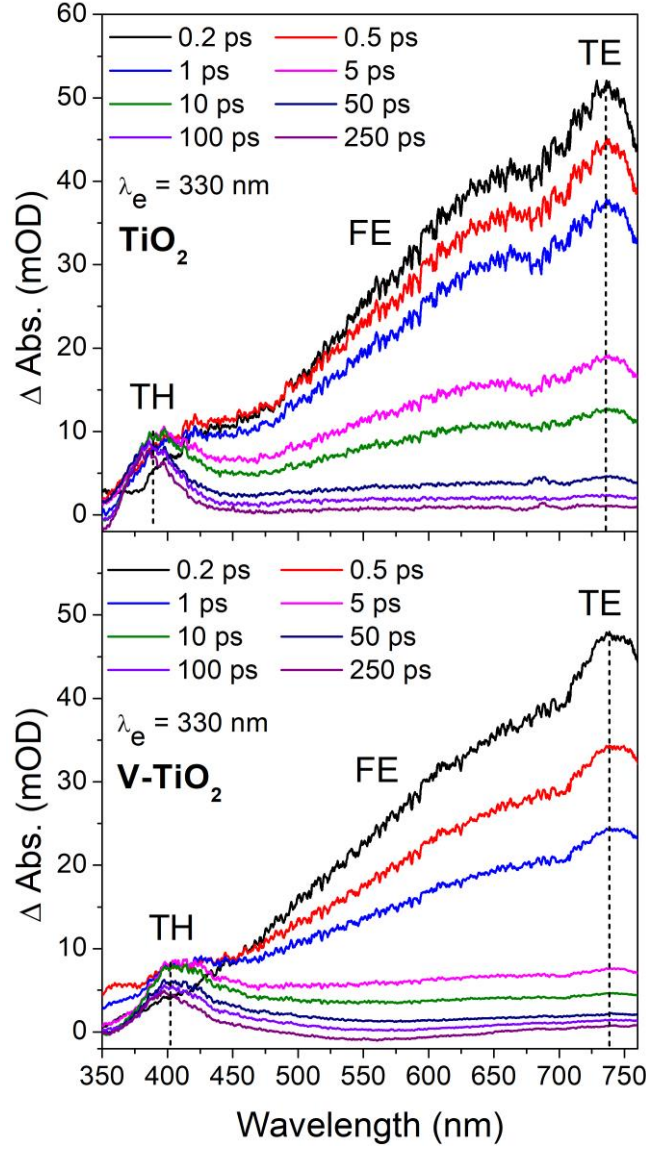


Figure 1: TA spectra of undoped (top) and V-doped (bottom) TiO_2 NPs with $\lambda_e = 330$ nm at different delay times.

Figure 1 shows that the only spectral difference introduced by doping is a small shift of the TH peak to higher wavelengths, from ~ 390 nm to ~ 400 nm. This could be due to a small doping – induced shift of the TH states. In Figure 2 we compare the time traces of the two samples at $\lambda_p = 730$ nm, which represents the E signal arising from both trapped and free electrons. The rise time of this signal (for both samples) is comparable to the instrumental resolution (~ 80 fs). This fast rise cannot be due to diffusion of electrons from the bulk to surface traps. In fact, an estimate of the diffusion time can be obtained from:

$$\tau_{diff} = \frac{r^2}{\pi^2 D} \quad (1)$$

in which r is the NP radius and D the diffusion coefficient, which for electrons in TiO_2 is $D_e = 1 \times 10^{-6} \text{ m}^2/\text{s}$ [51]. Since the average NPs diameter is 12 nm, the expected value for the diffusion time is ~ 10 ps, much longer than observed. We conclude that, in the first few ps after excitation, only a small fraction of electrons, i.e. those photo-excited in near-surface sites, can migrate to and remain trapped at the surface. Therefore, the E signal at $\lambda_p = 730$ nm in the first few ps is mostly due to FE. The initial ΔOD values for the TiO_2 and V- TiO_2 NPs are similar ($\sim 50\text{mOD}$), indicating that the initial concentration of photo-excited electrons is not affected by doping, which is reasonable in the case of ultrabandgap excitation. The decay (Figure 2) appears

significantly faster in V-TiO₂ NPs. We performed a fit of the time traces with a sum of a function for second order kinetics [30], which describes the fast decay in the first tens of ps, and a slow exponential decay:

$$A(t) = \frac{A_{2nd}}{(kCt + 1)} + A_{exp}e^{-t/\tau_e} \quad (2)$$

where the fit parameter kC represents the second-order rate constant k times the initial concentration C of electrons. We obtained very good fits for both samples, as shown in Figure 2.

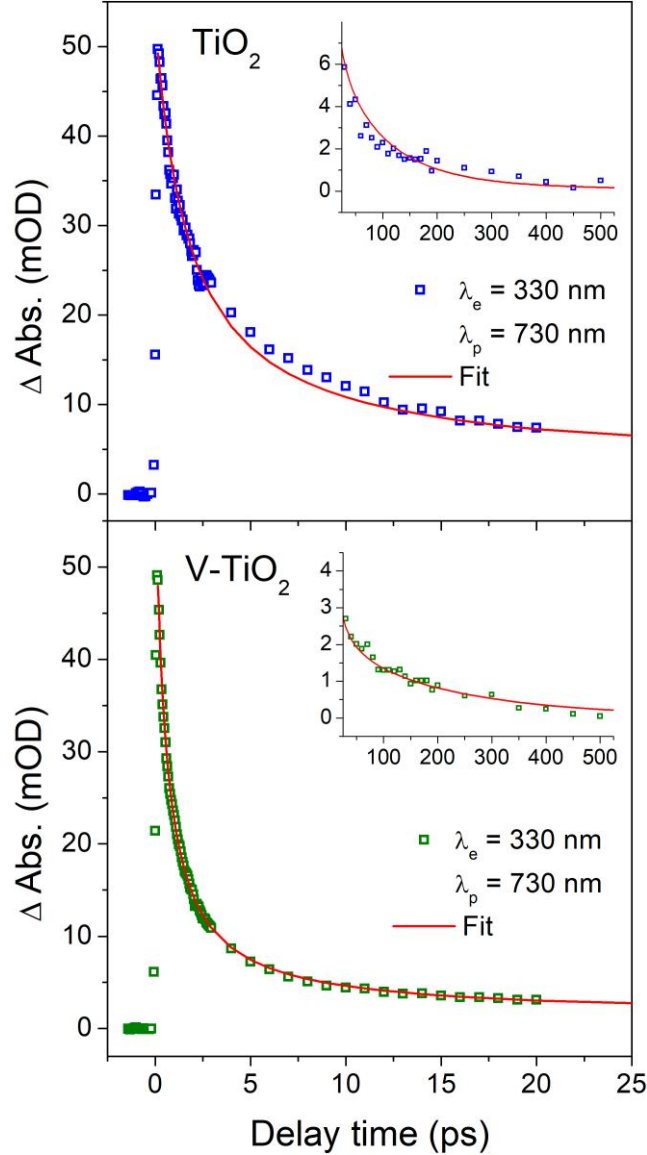


Figure 2: Comparison of the E signal time traces (at $\lambda_p=730$ nm) for undoped (top) and V-doped (bottom) TiO₂ NPs extracted from the data in Figure 1 ($\lambda_e=330$ nm). The best fits according to Equation 2 are displayed as red solid lines. The inset reports the same data over the extended 25-525 ps time interval.

The numerical results of the fits are summarized in Table I. The higher kC value in V-TiO₂ NPs that reflects the faster decay of the E signal is in very good agreement with the dependence of the rate constant on the doping level reported by Ikeda et al. [42]. The exponential decay with time constant τ_e , needed to model the time traces at $t > 100$ ps, has an amplitude A_{exp} much smaller than the amplitude A_{2nd} of the second-order kinetics.

Table I: Best-fit parameters for the time traces of E ($\lambda_p = 730$ nm) after excitation at different wavelengths λ_e according to Equation (2): amplitude A_{2nd} and rate-concentration product kC of fast second-order decay, amplitude A_{exp} and characteristic time τ_e of slow exponential decay. For $\lambda_e = 330$ nm, we also report the characteristic times τ_{h1} and τ_{h2} of the exponential decay of the trapped hole signal ($\lambda_p = 400$ nm) observed in V-TiO₂ NPs. In the case $\lambda_e = 530$ nm, the E signal was present only in V-TiO₂ NPs. Estimated errors are reported in brackets in units of the last digit.

$\lambda_e(\text{nm})$	Parameter	TiO ₂ NPs	V-TiO ₂ NPs
330	A_{2nd} (mOD)	49.6 (5)	58.8 (3)
	kC (ps ⁻¹)	0.56 (2)	1.80 (2)
	A_{exp} (mOD)	3.5 (3)	1.6 (1)
	τ_e (ps)	210 (30)	220 (30)
	τ_{h1} (ps)	no decay within 500 ps	36 (7)
	τ_{h2} (ps)	no decay within 500 ps	1030 (150)
400	A_{2nd} (mOD)	5.1 (1)	34.8 (3)
	kC (ps ⁻¹)	0.239 (16)	1.22 (4)
	A_{exp} (mOD)	1.7 (1)	3.9 (2)
	τ_e (ps)	360 (50)	320 (30)
530	A_{2nd} (mOD)	TA spectra non observed	1.0 (1)
	kC (ps ⁻¹)		0.8 (2)
	A_{exp} (mOD)		0.91 (5)
	τ_e (ps)		480 (90)

The time traces of the TH band are presented in Figure 3. The rise time of the TH signal was estimated by fitting the data to a step function convoluted with a Gaussian function that simulates the instrumental resolution (Figure S5). We obtained the same rise time of 230 ± 90 fs for TiO₂ NPs and 230 ± 30 fs for V-TiO₂ NPs, which is compatible with the data of Tamaki et al. [28]. This time interval is very similar to the diffusion time of holes from the bulk to the surface of the NPs, as estimated from Equation 1 using $D_h = 4 \cdot 10^{-5}$ m²/s [51], that is 250 fs. This is a further confirmation that this transient signal is due to TH. As already remarked for the E signal, the initial value of the TH signal is similar in TiO₂ and V-TiO₂ NPs, suggesting that the dopant atoms do not significantly alter the diffusion and trapping of holes on this short time scale. However, the influence of V-doping on the temporal dependence of the TH signal is more remarkable than for the E signal. In fact, while in TiO₂ NPs the TH signal remains almost constant up to 500 ps, in V-TiO₂ NPs it decays to 50% of the initial value in ~ 300 ps (Figure 3a). The TH time trace was fitted to a sum of two exponentials with characteristic times $\tau_{h1} = 36 \pm 7$ ps and $\tau_{h2} = 1030 \pm 150$ ps, as shown in Figure 3a and reported in Table I.

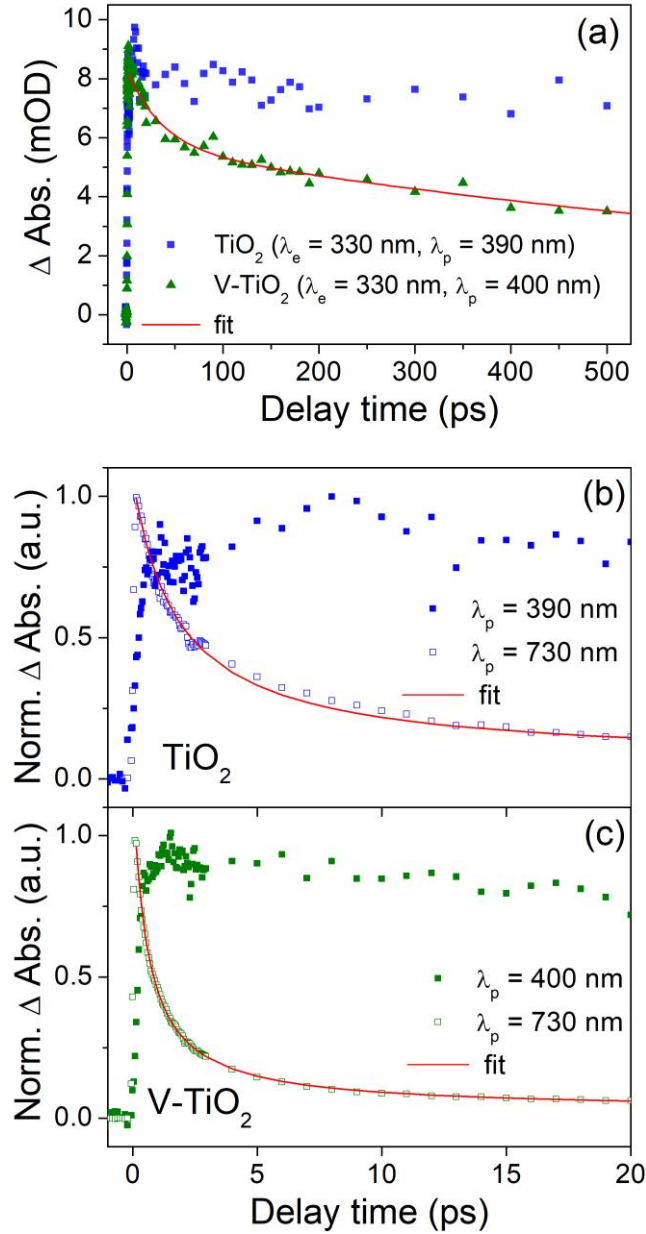


Figure 3: (a) TH signal time traces for undoped (blue squares) and V-doped (green triangles) TiO_2 NPs extracted from the data in Figure 1 ($\lambda_e = 330 \text{ nm}$). The red solid line is the best fit of the V-TiO₂ NPs with a sum of two exponentials with characteristic times τ_{h1} and τ_{h2} . (b) Comparison between the TH (filled squares) and E (empty squares) time traces for undoped TiO_2 NPs following photoexcitation at 330 nm. The red solid line displays the best fit for the E time trace according to Equation 2. (c) Same as (b) for V-TiO₂ NPs. For the best fit parameters, see Table I.

The two widely separated time scales observed for the E signal reflect profoundly different decay mechanisms. The fast decay with second-order kinetics hints at electron-hole recombination, which is expected under our conditions of strong excitation (1.8 mJ/cm^2). The fluence-dependent study reported in Figure S6 supports this interpretation by showing that the decay slows down with decreasing pulse energy. This is in agreement with results of Tamaki et al. that observed second-order decay of the E signal within 100 ps after ultrabandgap irradiation under strong excitation conditions [30]. One may wonder which kind of holes take part in this process. In fact, Figure 3b,c clearly shows that over the first 10 ps, where the E signal drops by $\sim 80\%$ and $\sim 90\%$ for TiO_2 and V-TiO₂, respectively, the TH signal is nearly constant in TiO_2 NPs and decreases by only $\sim 15\%$ in V-TiO₂ NPs. Therefore, the surface-trapped holes seem not to be involved (TiO_2) or only marginally involved (V-TiO₂) in the recombination. This observation leads us to suggest that the

electrons recombine mainly with holes that do not contribute a clearly identifiable TA signal within our explored wavelength range. These may be shallowly trapped holes or free holes that remain in the NPs due to saturation of the surface hole traps under strong excitation.

The slower exponential decay with characteristic time τ_e in the 100s of ps range (see Table I) was also observed by Tamaki et al. in the weak excitation limit [28]. They demonstrated that this dynamics reflects the relaxation of free electrons and shallowly trapped electrons to deep traps that do not contribute to the TA spectrum because of a very small optical absorption cross section. We can therefore subdivide the dynamics of charge carriers generated by strong ultrabandgap excitation into the following processes:

- 1) Holes migration and trapping on the surface of the NPs takes place in ~ 230 fs and leads to saturation of surface hole traps.
- 2) Recombination of free and shallowly trapped electrons with holes, mainly those that are not surface-trapped, starts immediately after excitation and proceeds with second-order kinetics over a few tens of ps.
- 3) When only surface-trapped holes remain, the dynamics of residual electrons becomes similar to the one observed under weak excitation conditions: relaxation into deep traps with time $\tau_e \sim 220$ ps is the dominant mechanism. This process yields an efficient electron-hole separation and explains the long-lived TH signal, in agreement with literature results in absence of hole scavengers [2,26,28,32].

Electron scavenging by oxygen is not expected to influence the dynamics on such a short time scale. In fact, the reaction of electrons with oxygen takes place on a much longer time interval, which ranges from 100 ns for surface-trapped electrons to several ms for bulk electrons [2,4,26].

The influence of V-doping on the aforementioned charge carrier dynamic after ultrabandgap irradiation can be summarized as follows:

- i) V-doping affects neither the initial concentration of photo-excited carriers nor the migration and trapping of holes in ~ 230 fs on the surface of the NPs;
- ii) V-doping accelerates by a factor of ~ 3 (see parameter kC in Table I) the second-order recombination kinetics that characterizes the fast decay of the E signal;
- iii) V-doping does not significantly alter the relaxation time of free or shallowly trapped electrons to deeper traps (see parameter τ_e in Table I).
- iv) V-doping reduces the lifetime of surface-trapped holes, the population of which decays according to a double exponential law in V-TiO₂ NPs. We suggest that the short time $\tau_{h1} = 36$ ps characterizes the recombination with free electrons -still available in this time interval- whereas the long time $\tau_{h2} = 1030$ ps can be ascribed to slower recombination with the deeply trapped electrons mentioned in iii).

Clearly, charge carriers prone to recombination in a few tens of ps are of limited relevance to most photocatalytic reactions, which require electron-hole separation and long lifetimes. Therefore, the connection between the V-doping effects on TA spectra and on photocatalytic properties should mainly address the long-lived reactive species. In this respect, item iv) above suggests that V-doping –at least in the present concentration- may have a negative effect on UV photocatalysis. This conclusion is supported by IPCE measurements presented later on. However, we will later see that V-doping induces photocatalytic activity and photoelectrochemical water splitting in a visible range, where pure TiO₂ NPs are completely inactive.

3.2 Transient absorption spectroscopy: longer wavelength (400 and 530 nm) excitation

We now describe measurements performed with $\lambda_e = 400$ nm and 530 nm, at which wavelengths the difference between the optical absorbance of TiO_2 and V- TiO_2 NPs is very significant. With $\lambda_e = 400$ nm some transitions between the tails of the valence and conduction bands in undoped TiO_2 are still possible while with $\lambda_e = 530$ nm undoped TiO_2 is transparent and thus only features related to V are probed in V- TiO_2 NPs.

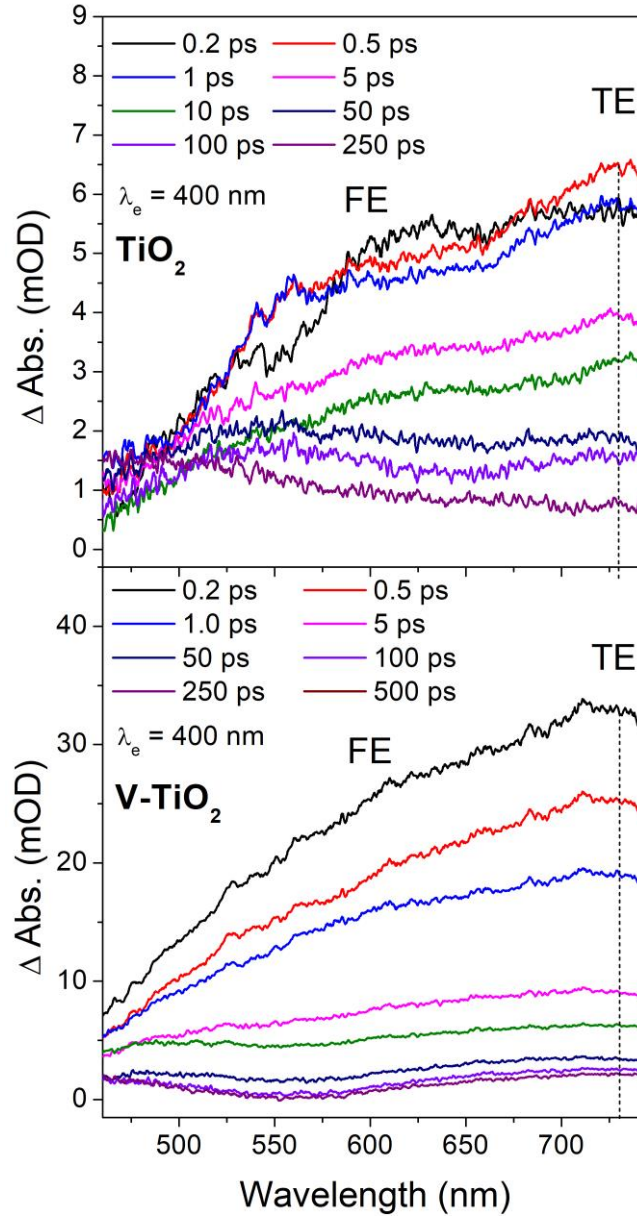


Figure 4: Transient absorption spectra of TiO_2 (top) and V- TiO_2 (bottom) NPs samples with $\lambda_e = 400$ nm at different delay times.

TA spectra excited with $\lambda_e = 400$ nm for TiO_2 and V- TiO_2 NPs are reported as a function of λ_p for selected time delays in the range $t = 0.2 - 500$ ps in Figure 4. The same data are displayed in 2 dimensions as a function of (λ_p, t) in Figure S4 of the supplementary material. At this excitation wavelength, the TH feature is not observable since it overlaps with the pump beam, while the remaining part of the spectra are qualitatively similar to those observed for ultrabandgap excitation. The main doping-induced difference is clearly the initial intensity of the measured transient signal that for V- TiO_2 NPs at $\lambda_p = 730$ nm is a factor of ~ 5 higher. This is consistent with the stronger optical absorbance of V- TiO_2 NPs at 400 nm shown in Figure S2. The time traces of the E signal of both samples can be fitted well using the model Equation (2) already applied for

excitation at $\lambda_e = 330$ nm. The best fits are shown in Figure 5 and the corresponding parameters are reported in Table I. The results corroborate the interpretation of the carrier dynamics proposed for ultrabandgap excitation. In fact, we notice that the ratio A_{exp}/A_{2nd} increases at $\lambda_e = 400$ nm compared to $\lambda_e = 330$ nm by a factor of 4.7 for TiO_2 NPs and of 4.0 for V- TiO_2 NPs. This indicates that a smaller fraction of electrons is involved in fast second-order recombination processes and that the slower exponential relaxation to deep traps gains importance. Furthermore, the rates of the second-order kinetics are slower compared to $\lambda_e = 330$ nm. Both results are consistent with the lower initial concentration of charge carriers after excitation at $\lambda_e = 400$ nm, qualitatively represented by the initial value of the E signal. The effects of V-doping on the characteristic decay times are similar to the case of ultrabandgap excitation: the second-order kinetics are speeded up (see kC parameter in Table I), suggesting that V favors recombination, while the relaxation time to deep bulk traps does not change (see parameter τ_e in Table I). The slightly higher τ_e values for both samples compared to $\lambda_e = 330$ nm may indicate that the relaxation time is longer for electrons with lower energy. As mentioned above, it was not possible to detect the TH signal. However, it is reasonable to assume that a situation similar to the case $\lambda_e = 330$ nm is at play, i.e. that long-lived surface-trapped holes are present and that V-doping favors their recombination.

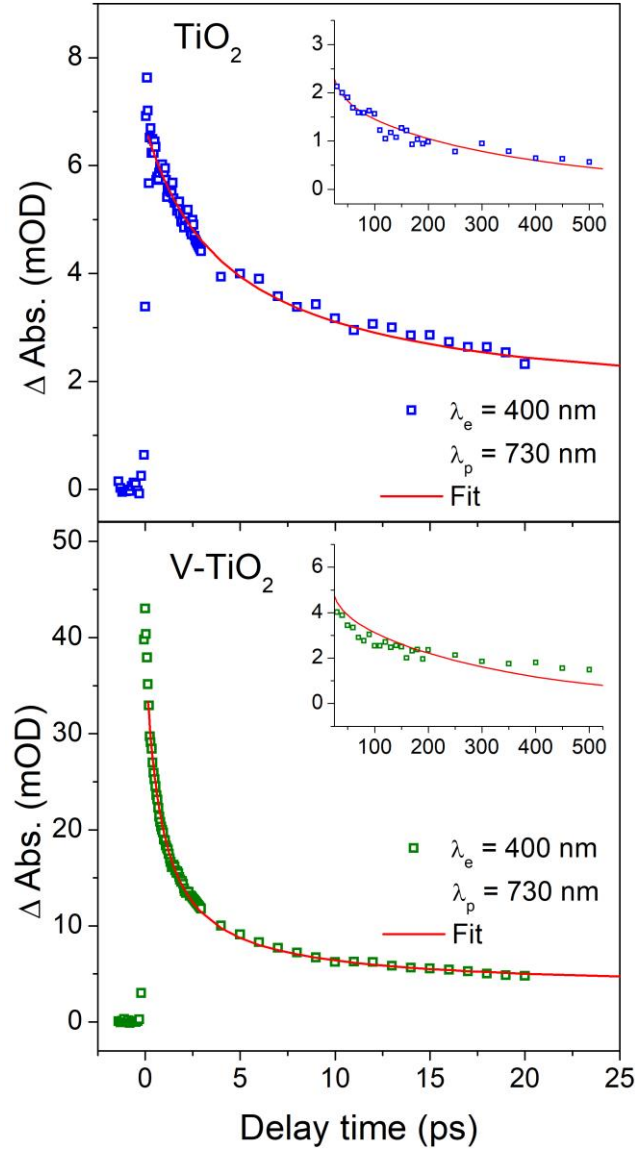


Figure 5: Comparison of the E signal time traces (at $\lambda_p = 730$ nm) for undoped (top) and V-doped (bottom) TiO_2 NPs extracted from the data in Figure 4 ($\lambda_e = 400$ nm). The best fits according to Equation 2 are displayed as red solid lines. The inset reports the same data over the extended 25-525 ps time interval.

For excitation at $\lambda_e = 530$ nm it was impossible to measure any TA signal in the TiO_2 NPs. However, as shown in Figure 6, using 7 mJ/cm^2 pulses we were able to observe the time trace of a weak E signal in V- TiO_2 NPs. The corresponding TA spectra at selected delay times, restricted to $\lambda_p > 600$ nm due to overlapping with the pump beam and to the very weak intensity, are displayed in Figure S7. The best fit of the E signal according to Equation (2) is displayed in Figure 6 and the corresponding parameters are reported in Table I. The amplitudes A_{2nd} and A_{exp} are rather small and exhibit a similar value of about 1 mOD, in qualitative agreement with the previous remark that A_{exp}/A_{2nd} increases with decreasing concentration of photo-excited electrons. The characteristic relaxation time $\tau_e = 480$ ps is slightly longer than after excitation at $\lambda_e = 400$ nm.

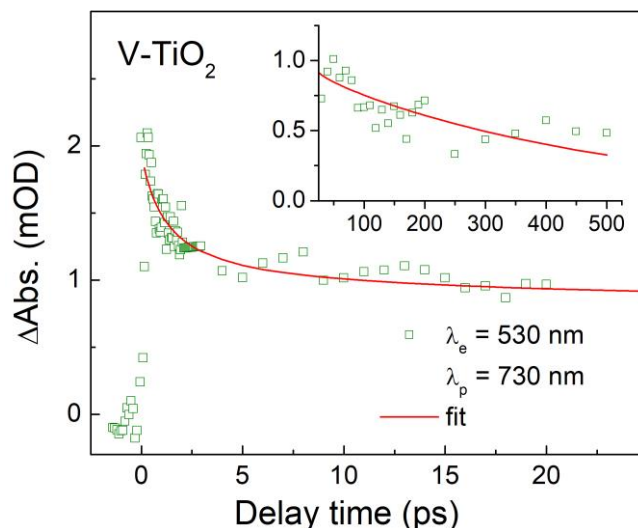


Figure 6: Time trace of the E signal ($\lambda_p = 730$ nm) and relative best fit obtained with 7 mJ/cm^2 and $\lambda_e = 530$ nm pump pulse in V- TiO_2 NPs. The inset displays the same data and fit in the extended 25-525 ps interval.

The final important message is that irradiation of V- TiO_2 NPs in the 400 – 530 nm range is capable of generating long-lived electrons with relaxation dynamics similar to that observed after irradiation at 330 nm. This suggests that photon absorption, also at the low energy of 2.34 eV (530 nm), results in electron excitation into the conduction band, followed by shallow trapping and relaxation. Since 2.34 eV is well below the band gap of pure TiO_2 (3.0 – 3.2 eV), the initial electron state must be an intra-gap state that originates with V-doping. This also means that upon photon absorption a transition of a substitutional dopant cation from a V^{4+} to a V^{5+} oxidation state must take place, leaving a hole on the V site. This picture is in full agreement with the results of our recent XANES experiment on the same V- TiO_2 NPs, in which we observed a blue-shift of the V K-edge during laser irradiation at 532 nm [45]. We estimated that the photo-excited V^{5+} has an extremely long lifetime of ~ 0.8 ms. In the same experiment we highlighted a concomitant red-shift of the Ti K-edge, suggesting that the electron remains trapped at a defective Ti state. The high-energy-resolution analysis of the XANES lineshape indicated that such Ti traps are mostly localized on the NPs surface.

Irradiation at 400 nm (3.1 eV) represents an intermediate case, in which electronic excitations both from the valence band and from intra-gap V-related states are possible. The much higher absorption and TA signal in V- TiO_2 compared to TiO_2 , however, suggests that the latter plays the dominant role.

The relevant question now is whether this picture corresponds to a tangible photocatalytic activity in the visible spectral range. We will address this issue in the following section.

3.3 Visible light photocatalysis and photoelectrochemistry

Figure 7a displays optical absorption spectra of $\text{NO}_2\text{-C}_6\text{H}_4\text{-CHO}$ and of $\text{NH}_2\text{-C}_6\text{H}_4\text{-CHO}$, which show absorption maxima at 264 nm and 312 nm respectively. De-aerated suspensions of V- TiO_2 NPs containing $\text{NO}_2\text{-C}_6\text{H}_4\text{-CHO}$ were illuminated with visible light ($\lambda > 450$ nm) and the reduction of the nitro group in $\text{NO}_2\text{-C}_6\text{H}_4\text{-CHO}$ to

$\text{NH}_2\text{-C}_6\text{H}_4\text{-CHO}$ was monitored. In order to gain information about the conversion of $\text{NO}_2\text{-C}_6\text{H}_4\text{-CHO}$ to $\text{NH}_2\text{-C}_6\text{H}_4\text{-CHO}$, we tracked the evolution of the A_{312}/A_{264} ratio with increasing irradiation time. Figure 7b shows that this ratio slowly increases during visible light illumination ($\lambda > 450 \text{ nm}$) of V-TiO₂ NPs. This result is an indication that this photocatalyst is able to reduce the nitro group using photoexcited electrons from visible absorbing states. From a mechanistic point of view, it has been demonstrated that the protons required to form the NH_2 group are provided by the dissociative adsorption of sacrificial $\text{C}_3\text{H}_8\text{O}$ (isopropanol, 2-Pr-OH) on the NPs surface and its subsequent oxidation into $\text{C}_3\text{H}_6\text{O}$ (acetone) [52]. Further details on the mechanism of H^+ formation are provided in the Supplementary Material. We also remark that, although in a photocatalytic process oxidation and reduction reactions take place on the same NP, a perfect synchronization of electron and proton transfer is not necessary. In fact, TiO₂-based NPs can act as temporary reservoirs of electrons, giving rise to electron accumulation in the conduction band followed by trapping in states below the CBM.

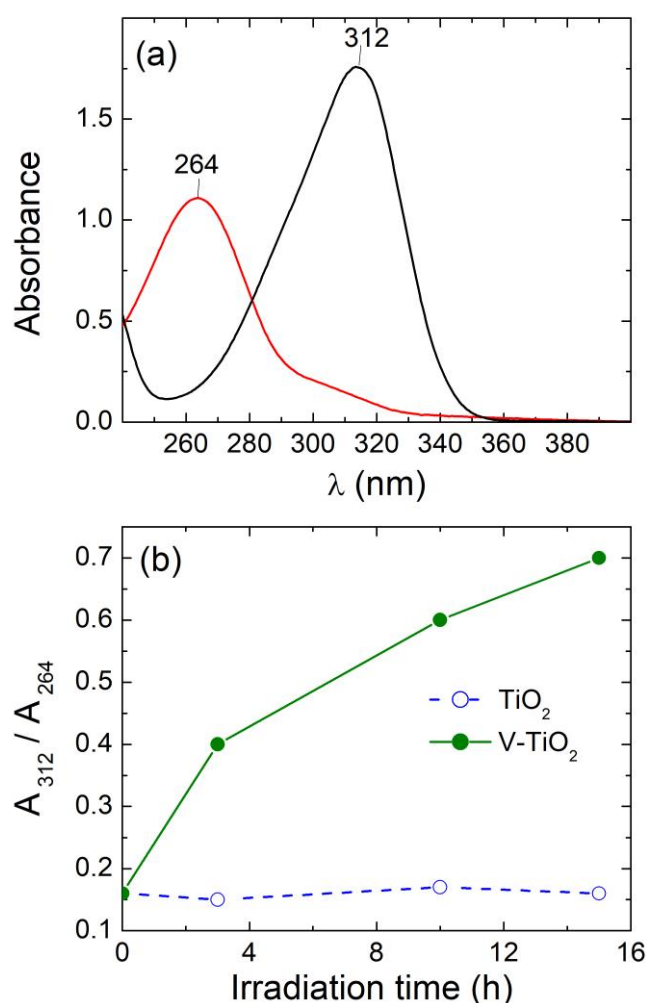


Figure 7: (a) Absorption spectra of $\text{NO}_2\text{-C}_6\text{H}_4\text{-CHO}$ (black) and $\text{NH}_2\text{-C}_6\text{H}_4\text{-CHO}$ (blue) (both around $1 \times 10^{-4} \text{ M}$) dissolved in a $\text{CH}_3\text{CN}/\text{C}_3\text{H}_8\text{O}$ (4/1) solvent mixture. (b) The absorbance ratio as a function of irradiation time for V-TiO₂ (full circles) and TiO₂ (empty circles) NPs. Values of absorbance are taken at the wavelengths of the two compounds that correspond to the absorbance maxima shown in (a).

An important point to note is that the ratio A_{312}/A_{264} is constant when undoped TiO₂ NPs are illuminated by visible light under exactly the same photocatalytic conditions (Figure 7b, empty circles). This result indicates that undoped TiO₂ NPs alone are not able to perform any reduction on $\text{NO}_2\text{-C}_6\text{H}_4\text{-CHO}$ under $\lambda > 450 \text{ nm}$ illumination, confirming that photoactive states introduced by V-doping are mandatory for triggering such

photocatalytic reaction. Control experiments in the dark and in the absence of photocatalyst confirm that the reaction proceeds only under the simultaneous presence of both V-TiO₂ NPs and visible light (Figure S8).

If the spectral range of the incident light is extended in the UV, e.g. by using a $\lambda > 360$ nm filter, the photocatalytic reduction takes place in few minutes [52] and a significant difference between undoped and V-doped TiO₂ NPs can no longer be detected.

Electron paramagnetic resonance (EPR) spin-trapping experiments show that, for both samples, the formation of radicals coming from 2-propanol takes place immediately after illumination in the wavelength range $\lambda > 360$ nm (Figure S9). Under these conditions, the photocatalytic behaviour of V-TiO₂ is qualitatively the same as for undoped TiO₂, being dominated by transitions from the valence to the conduction band. Differently, under excitation at $\lambda > 450$ nm, EPR signals were not detected (Figure S9). While for TiO₂ the absence of an EPR signal is consistent with the lack of optical absorption in this range, for V-TiO₂ it suggests that the average concentration of radicals is below the sensitivity limit of a typical EPR spin trapping experiment. In fact one can consider that photogenerated radicals are not usually quantitatively trapped and that the paramagnetic adduct between radical and spin trap is continuously formed and consumed. This is consistent with the long times (hours) necessary to observe the photocatalytic reduction process, which is clearly related to the cumulative effect of the radicals.

The IPCE spectra of photoanodes made with TiO₂ and V-TiO₂ NPs are reported in Figure 8. The low IPCE values for both samples are likely due to the poor ohmic contact achieved with the preparation method. Here we are interested in comparing the spectral shapes. Two features allow us to establish a connection with the TA spectroscopy results. The first is that V-TiO₂ NPs exhibit a higher IPCE in the $\lambda \gtrsim 360$ nm range. In particular, photoelectrochemical water splitting in the 430-480 nm range is still possible with V-TiO₂ NPs whereas the IPCE of TiO₂ NPs is almost zero. A connection with the enhanced optical absorbance (Figure S2) and TA signal (Figures 5 and 6) in this wavelength range is straightforward, but the result also brings information on the energy level of the V dopant, as discussed later on. The second is that V-TiO₂ NPs have lower IPCE in the UV range $\lambda \lesssim 350$ nm. This may reflect the doping-enhanced recombination of surface trapped holes with deeply trapped electrons previously connected with the decay of the TH signal in UV-irradiated V-TiO₂ NPs (see τ_h in Table I). In fact, with decreasing wavelength and increasing extinction coefficient, the incident radiation is absorbed closer to the electrolytic solution and farther from the ITO back contact. This means that on average the electrons must travel a longer distance across the film, increasing the probability of recombination before reaching the ITO layer.

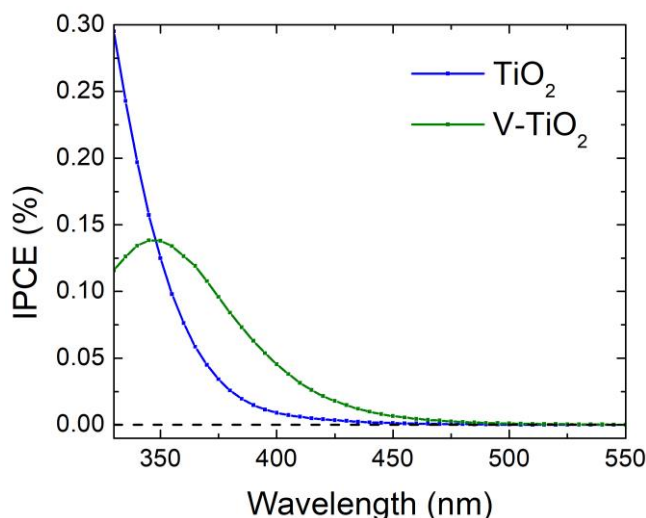


Figure 8: IPCE spectra of photoanodes prepared with TiO₂ and V-TiO₂ NPs.

The IPCE spectra were also measured in the CH₃CN/C₃H₈O (4/1) mixture used for the photocatalytic tests with LiClO₄ 0.1 M as electrolyte. No significant changes were detected compared to the results shown in Figure 8 for 0.1 M KOH in water.

3.4 Correlation between charge carrier dynamics and photocatalysis

The combination of TA spectra and photocatalytic / photoelectrochemical measurements leads to a unified picture of the charge carrier dynamics after visible light irradiation and of the dopant energy level in V-TiO₂ NPs, as schematized in Figure 9 and described in the following.

The photocatalytic reaction shown in Figure 7b, albeit slow, testifies that electrons photoexcited by visible light irradiation of V-TiO₂ NPs possess suitable energies and lifetimes to reduce the nitro group in solution. The TA spectral shape and the E signal relaxation dynamics indicate that visible absorbing electrons are photoexcited into the conduction band. At present, we do not know the characteristic time τ_{IT} , over which interfacial electron transfer from the V-TiO₂ NPs to the solution takes place. If $\tau_{IT} \ll \tau_e$ (see Table I), there is no time for the electrons to relax into deep traps and the reaction consumes shallow-trapped electrons. Vice versa, if $\tau_{IT} \gg \tau_e$, the electrons relax first into deep traps, and subsequently reduce the molecules in solution. Intermediate situations are clearly possible. The red-shift of the Ti K edge under stationary visible-light irradiation observed by XANES [45] allows us to assign the deep trapping to $Ti_s^{4+} + e^- \rightarrow Ti_s^{3+}$ at a defective surface site Ti_s . A previous electrochemical study showed that $-NO_2$ reduction takes place at about 0.5 eV below the CBM [52]. Since sub-bandgap visible light cannot promote electronic transitions from the valence to the conduction band, the initial electron state must be an intra-gap state associated with V, which is incorporated as a substitutional V^{4+} cation in the lattice of both rutile and anatase [43,44]. There is a significant spread in the calculated energy level of the electronic state localized on V^{4+} , which was reported between 0.7 eV [16,20] and 1.36 eV [21] below the CBM. However, our results show that it must lie deeper than suggested by calculations. In fact, IPCE measurements tell us that the hole h_V^+ left on the V site after photoexcitation: $V^{4+} + h\nu \rightarrow V^{5+} + e_{CB}^- = h_V^+ + e_{CB}^-$ has a suitable potential to drive oxygen evolution. Taking into account the pH conditions (pH=13) and the known TiO₂ band edge positions in aqueous environment [53], we conclude that the oxygen evolution potential corresponds to an energy level at 1.5 eV below CBM. It is therefore reasonable to assume that the actual quasi-Fermi level of the trapped holes in the V-TiO₂ NPs is somewhat lower in energy with respect to such value, in order to provide sufficient overpotential for oxygen evolution. The optical absorbance spectra provide further information in this respect: in fact, Figure S2 shows that absorption extinguishes at ~550 nm (~2.2 eV), proving that there are no absorbing electrons closer than ~2.2 eV to the CBM. We may therefore locate the V dopant level at ~2.2 eV below the CBM. Such an estimate is consistent with static absorbance, TA spectroscopy and IPCE measurements, and is also in agreement with an early experimental investigation by electron paramagnetic resonance, which located the V^{4+} level at ~2.1 eV below the CBM [8]. According to this picture, one would expect photoelectrochemical water splitting to be possible also in the 480-550 nm range, where instead Figure 8 shows almost zero IPCE. However, the photocurrent may drop below the detection limit due to the much weaker excitation in the IPCE setup compared to TA spectroscopy and to the aforementioned ohmic losses in the NPs-assembled photoanodes.

To close the cycle, we suggest that the hole h_V^+ on the V site migrates to a trapping site on the NPs surface, where it promotes the oxidation of C₃H₈O to C₃H₆O, liberating two H⁺ ions. This reaction provides the protons that are needed to form the NH₂ group. The net result is thus a transfer of electrons and protons from the sacrificial C₃H₈O to NO₂-C₆H₄-CHO mediated by the V-TiO₂ nanoparticle photocatalysts.

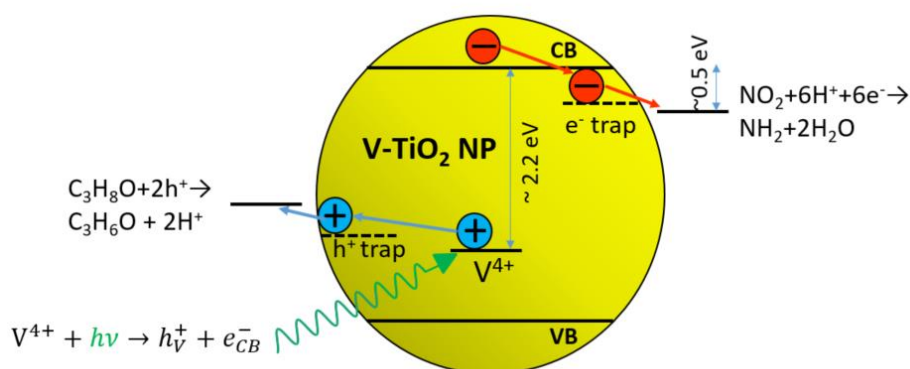


Figure 9: Schematic representation of the photocatalytic reduction of 4-nitrobenzaldehyde by V-TiO₂ NPs under visible irradiation.

4. Conclusions

This study sheds light on the carrier dynamics, electronic structure and photocatalytic properties of V-doped TiO₂ NPs compared to undoped ones. The primary findings, achieved thanks to a combination of transient absorption spectroscopy and photocatalytic/photoelectrochemical characterization, can be summarized as follows:

- i) Under strong excitation at $\lambda_e=330$ and 400 nm, a fast electron-hole recombination according to a second-order kinetics is observed, the recombination rate being higher in V-doped NPs. The electrons that survive recombination undergo a slower relaxation into deep traps;
- ii) Valence band holes migrate to and are trapped on the surface over an ultrafast time scale (~ 230 fs). Trapped holes exhibit a long lifetime > 500 ps in undoped NPs, whereas V-doping seems to accelerate their recombination with trapped electrons;
- iii) In V-doped NPs only, the photoexcitation of electrons under irradiation at $\lambda_e= 530$ nm is observed. We associate this peculiar feature of V-doped NPs with an intra-gap state localized on V⁴⁺ substitutional cations, from which electrons can be photo-excited into the CB by sub-band gap irradiation. We locate this level at about 2.2 eV below the CBM;
- iv) The presence of charge carriers photo-excited from visible absorbing states in V-doped NPs corresponds to a clear photocatalytic activity in a spectral region where undoped TiO₂ NPs are inactive. V-TiO₂ NPs are able to reduce the nitro group NO₂ in 4-nitrobenzaldehyde under visible light irradiation ($\lambda > 450$ nm), and water splitting with V-TiO₂ photoanodes is possible up to $\lambda \sim 480$ nm.

Future studies may investigate the dependence of photoactivity on the V-doping level with the aim to optimize the competition between positive and negative features induced by doping, i.e. enhanced visible light absorption vs accelerated electron-hole recombination.

Acknowledgements

This research was funded by the Italian Ministry of Research (MIUR) within PRIN-2015 Project No. NEWLI-2015CL3APH.

References

- [1] M.A. Henderson, A surface science perspective on TiO₂ photocatalysis, *Surf. Sci. Rep.* 66 (2011) 185–297. doi:10.1016/j.surfrep.2011.01.001.
- [2] J. Schneider, M. Matsuoka, M. Takeuchi, J. Zhang, Y. Horiuchi, M. Anpo, D.W. Bahnemann, Understanding TiO₂ Photocatalysis: Mechanisms and Materials, *Chem. Rev.* 114 (2014) 9919–9986. doi:10.1021/cr5001892.
- [3] N. Serpone, A. V. Emeline, V.K. Ryabchuk, V.N. Kuznetsov, Y.M. Artem'ev, S. Horikoshi, Why do Hydrogen and Oxygen Yields from Semiconductor-Based Photocatalyzed Water Splitting Remain Disappointingly Low? Intrinsic and Extrinsic Factors Impacting Surface Redox Reactions, *ACS Energy Lett.* 1 (2016) 931–948. doi:10.1021/acsenergylett.6b00391.
- [4] A. Fujishima, X. Zhang, D.A. Tryk, TiO₂ photocatalysis and related surface phenomena, *Surf. Sci. Rep.* 63 (2008) 515–582. doi:10.1016/j.surfrep.2008.10.001.
- [5] J. Tang, J.R. Durrant, D.R. Klug, Mechanism of Photocatalytic Water Splitting in TiO₂. Reaction of Water with Photoholes, Importance of Charge Carrier Dynamics, and Evidence for Four-Hole Chemistry, *J. Am. Chem. Soc.* 130 (2008) 13885–13891. doi:10.1021/ja8034637.
- [6] H. Zhang, G. Chen, D.W. Bahnemann, Photoelectrocatalytic materials for environmental applications, *J. Mater. Chem.* 19 (2009) 5089–5121. doi:10.1039/b821991e.
- [7] R. Asahi, T. Morikawa, T. Ohwaki, K. Aoki, Y. Taga, Visible-light photocatalysis in nitrogen doped titanium oxides, *Science* (80-.). 293 (2001) 269–271.
- [8] K. Mizushima, M. Tanaka, A. Asai, S. Iida, J.B. Goodenough, Impurity levels of iron-group ions in TiO₂(II), *J. Phys. Chem. Solids.* 40 (1979) 1129–1140. doi:10.1016/0022-3697(79)90148-3.
- [9] O. Elbanna, P. Zhang, M. Fujitsuka, T. Majima, Facile preparation of nitrogen and fluorine codoped TiO₂ mesocrystal with visible light photocatalytic activity, *Appl. Catal. B Environ.* 192 (2016) 80–87. doi:10.1016/j.apcatb.2016.03.053.
- [10] W. Choi, A. Termin, M.R. Hoffmann, The Role of Metal Ion Dopants in Quantum-Sized TiO₂: Correlation between Photoreactivity and Charge Carrier Recombination Dynamics, *J. Phys. Chem.* 98 (1994) 13669–13679. doi:10.1021/j100102a038.
- [11] J. Choi, H. Park, M.R. Hoffmann, Effects of single metal-ion doping on the visible-light photoreactivity of TiO₂, *J. Phys. Chem. C.* 114 (2010) 783–792. doi:10.1021/jp908088x.
- [12] R. Asahi, T. Morikawa, H. Irie, T. Ohwaki, Nitrogen-doped titanium dioxide as visible-light-sensitive photocatalyst: Designs, developments, and prospects, *Chem. Rev.* 114 (2014) 9824–9852. doi:10.1021/cr5000738.
- [13] M. Graetzel, R.F. Howe, Electron paramagnetic resonance studies of doped titanium dioxide colloids, *J. Phys. Chem.* 94 (1990) 2566–2572. doi:10.1021/j100369a064.
- [14] D. Dvoranová, V. Brezová, M. Mazúr, M.A. Malati, Investigations of metal-doped titanium dioxide photocatalysts, *Appl. Catal. B Environ.* 37 (2002) 91–105. doi:10.1016/S0926-3373(01)00335-6.
- [15] R. Jaiswal, N. Patel, D.C. Kothari, A. Miotello, Improved visible light photocatalytic activity of TiO₂ co-doped with Vanadium and Nitrogen, *Appl. Catal. B Environ.* 126 (2012) 47–54. doi:10.1016/j.apcatb.2012.06.030.
- [16] N. Patel, R. Jaiswal, T. Warang, G. Scardueli, A. Dashora, B.L. Ahuja, D.C. Kothari, A. Miotello, Efficient photocatalytic degradation of organic water pollutants using V-N-codoped TiO₂ thin films, *Appl. Catal. B Environ.* 150–151 (2014) 74–81. doi:10.1016/j.apcatb.2013.11.033.

- [17] B. Tian, C. Li, F. Gu, H. Jiang, Y. Hu, J. Zhang, Flame sprayed V-doped TiO₂ nanoparticles with enhanced photocatalytic activity under visible light irradiation, *Chem. Eng. J.* 151 (2009) 220–227. doi:10.1016/J.CEJ.2009.02.030.
- [18] W.-C. Lin, Y.-J. Lin, Effect of Vanadium(IV)-Doping on the Visible Light-Induced Catalytic Activity of Titanium Dioxide Catalysts for Methylene Blue Degradation, *Environ. Eng. Sci.* 29 (2012) 447–452. doi:10.1089/ees.2010.0350.
- [19] W. Zhou, Q. Liu, Z. Zhu, J. Zhang, Preparation and properties of vanadium-doped TiO₂ photocatalysts, *J. Phys. D: Appl. Phys.* 43 (2010) 035301. doi:10.1088/0022-3727/43/3/035301.
- [20] T. Umebayashi, T. Yamaki, H. Itoh, K. Asai, Analysis of electronic structures of 3d transition metal-doped TiO₂ based on band calculations, *J. Phys. Chem. Solids.* 63 (2002) 1909–1920. doi:10.1016/S0022-3697(02)00177-4.
- [21] J. Osorio-Guillén, S. Lany, A. Zunger, Atomic Control of Conductivity Versus Ferromagnetism in Wide-Gap Oxides Via Selective Doping: V, Nb, Ta in Anatase TiO_2 , *Phys. Rev. Lett.* 100 (2008) 036601. doi:10.1103/PhysRevLett.100.036601.
- [22] G. Rothenberger, J. Moser, M. Graetzel, N. Serpone, D. Sharma, Charge carrier trapping and recombination dynamics in small semiconductor particles, *J. Am. Chem. Soc.* 107 (1985) 8054–8059. doi:10.1021/ja00312a043.
- [23] N. Serpone, D. Lawless, R. Khairutdinov, Size Effects on the Photophysical Properties of Colloidal Anatase TiO₂ Particles: Size Quantization versus Direct Transitions in This Indirect Semiconductor?, *J. Phys. Chem.* 99 (1995) 16646–16654. doi:10.1021/j100045a026.
- [24] D. Colombo, R. Bowman, Does interfacial charge transfer compete with charge carrier recombination? A femtosecond diffuse reflectance investigation of TiO₂ nanoparticles, *J. Phys. Chem.* 3654 (1996) 18445–18449. doi:10.1021/jp9610628.
- [25] N. Serpone, D. Lawless, R. Khairutdinov, E. Pelizzetti, Subnanosecond relaxation dynamics in TiO₂ colloidal sols (Particle sizes $R_p = 1.0\text{--}13.4\text{ nm}$). Relevance to heterogeneous photocatalysis, *J. Phys. Chem.* 99 (1995) 16655–16661. doi:10.1021/j100045a027.
- [26] T. Yoshihara, R. Katoh, A. Furube, Y. Tamaki, M. Murai, K. Hara, S. Murata, H. Arakawa, Identification of Reactive Species in Photoexcited Nanocrystalline TiO₂ Films by Wide-Wavelength-Range (400–2500 nm) Transient Absorption Spectroscopy, *J. Phys. Chem. B.* 108 (2004) 3817–3823. doi:10.1021/jp031305d.
- [27] X. Yang, N. Tamai, How fast is interfacial hole transfer? In situ monitoring of carrier dynamics in anatase TiO₂ nanoparticles by femtosecond laser spectroscopy, *Phys. Chem. Chem. Phys.* 3 (2001) 3393–3398. doi:10.1039/b101721g.
- [28] Y. Tamaki, A. Furube, M. Murai, K. Hara, R. Katoh, M. Tachiya, Dynamics of efficient electron-hole separation in TiO₂ nanoparticles revealed by femtosecond transient absorption spectroscopy under the weak-excitation condition., *Phys. Chem. Chem. Phys.* 9 (2007) 1453–1460. doi:10.1039/b617552j.
- [29] M. Murai, Y. Tamaki, A. Furube, K. Hara, R. Katoh, Reaction of holes in nanocrystalline TiO₂ films evaluated by highly sensitive transient absorption spectroscopy, *Catal. Today.* 120 (2007) 214–219. doi:10.1016/J.CATTOD.2006.07.048.
- [30] Y. Tamaki, K. Hara, R. Katoh, M. Tachiya, A. Furube, Femtosecond Visible-to-IR Spectroscopy of TiO₂ Nanocrystalline Films: Elucidation of the Electron Mobility before Deep Trapping †, *J. Phys. Chem. C.* 113 (2009) 11741–11746. doi:10.1021/jp901833j.

- [31] A. Furube, T. Asahi, H. Masuhara, H. Yamashita, M. Anpo, Charge carrier dynamics of standard TiO₂ catalysts revealed by femtosecond diffuse reflectance spectroscopy, *J. Phys. Chem. B.* 103 (1999) 3120–3127. doi:10.1021/jp984162h.
- [32] D.W. Bahnemann, M. Hilgendorff, R. Memming, Charge carrier dynamics at TiO₂ particles: reactivity of free and trapped holes, *J. Phys. Chem. B.* 101 (1997) 4265–4275. doi:10.1021/jp9639915.
- [33] A.L. Linsebigler, A.L. Linsebigler, J.T. Yates Jr, G. Lu, G. Lu, J.T. Yates, Photocatalysis on TiO₂ Surfaces: Principles, Mechanisms, and Selected Results, *Chem. Rev.* 95 (1995) 735–758. doi:10.1021/cr00035a013.
- [34] T. Berger, M. Sterrer, O. Diwald, E. Knözinger, D. Panayotov, T.L. Thompson, J.T. Yates, Light-Induced Charge Separation in Anatase TiO₂ Particles, *J. Phys. Chem. B.* 109 (2005) 6061–6068. doi:10.1021/jp0404293.
- [35] R.F. Howe, M. Gratzel, EPR observation of trapped electrons in colloidal titanium dioxide, *J. Phys. Chem.* 89 (1985) 4495–4499. doi:10.1021/j100267a018.
- [36] D.E. Skinner, D.P. Colombo, J.J. Cavaleri, R.M. Bowman, Femtosecond Investigation of Electron Trapping in Semiconductor Nanoclusters, *J. Phys. Chem.* 99 (1995) 7853–7856. doi:10.1021/j100020a003.
- [37] J. Sun, Y. Yang, J.I. Khan, E. Alarousu, Z. Guo, X. Zhang, Q. Zhang, O.F. Mohammed, Ultrafast carrier trapping of a metal-doped titanium dioxide semiconductor revealed by femtosecond transient absorption spectroscopy, *ACS Appl. Mater. Interfaces.* 6 (2014) 10022–10027. doi:10.1021/am5026159.
- [38] K. Gopinadhan, B. Kumar, N. Palina, M. Motapathula, I. Pallecchi, T.P. Sarkar, Y. Zhihua, J.Q. Chen, A. Annadi, A. Rana, A. Srivastava, D. Marré, J. Chen, A. Ariando, S. Dhar, A. Rusydi, T. Venkatesan, Effect of Nb and Ta substitution on donor electron transport and ultrafast carrier dynamics in anatase TiO₂ thin films, *J. Mater. Chem. C.* 3 (2015) 6329–6333. doi:10.1039/C5TC01061F.
- [39] K.I. Yamanaka, T. Ohwaki, T. Morikawa, Charge-carrier dynamics in Cu- or Fe-loaded nitrogen-doped TiO₂ powder studied by femtosecond diffuse reflectance spectroscopy, *J. Phys. Chem. C.* 117 (2013) 16448–16456. doi:10.1021/jp404431z.
- [40] K. Yamanaka, T. Morikawa, Charge-Carrier Dynamics in Nitrogen-Doped TiO₂ Powder Studied by Femtosecond Time-Resolved Diffuse Reflectance Spectroscopy, *J. Phys. Chem. C.* 116 (2012) 1286–1292. doi:10.1021/jp209210u.
- [41] M. Salmi, N. Tkachenko, R.J. Lamminmäki, S. Karvinen, V. Vehmanen, H. Lemmetyinen, Femtosecond to nanosecond spectroscopy of transition metal-doped TiO₂ particles, *J. Photochem. Photobiol. A Chem.* 175 (2005) 8–14. doi:10.1016/j.jphotochem.2005.03.022.
- [42] S. Ikeda, N. Sugiyama, B. Pal, G. Marci, L. Palmisano, H. Noguchi, K. Uosaki, B. Ohtani, Photocatalytic activity of transition-metal-loaded titanium(IV) oxide powders suspended in aqueous solutions: Correlation with electron–hole recombination kinetics, *Phys. Chem. Chem. Phys.* 3 (2001) 267–273. doi:10.1039/b008028o.
- [43] G. Rossi, M. Calizzi, V. Di Cintio, S. Magkos, L. Amidani, L. Pasquini, F. Boscherini, Local Structure of *v* Dopants in TiO₂ Nanoparticles: X-ray Absorption Spectroscopy, Including Ab-Initio and Full Potential Simulations, *J. Phys. Chem. C.* 120 (2016). doi:10.1021/acs.jpcc.5b12045.
- [44] Z. El Koura, G. Rossi, M. Calizzi, L. Amidani, L. Pasquini, A. Miotello, F. Boscherini, XANES study of vanadium and nitrogen dopants in photocatalytic TiO₂ thin films, *Phys. Chem. Chem. Phys.* 20 (2018) 221–231. doi:10.1039/C7CP06742A.
- [45] G. Rossi, M. Calizzi, L. Amidani, A. Migliori, F. Boscherini, L. Pasquini, Element-specific channels for

the photoexcitation of V-doped TiO_2 nanoparticles, *Phys. Rev. B.* 96 (2017) 045303. doi:10.1103/PhysRevB.96.045303.

- [46] L. Amidani, A. Naldoni, M. Malvestuto, M. Marelli, P. Glatzel, V. Dal Santo, F. Boscherini, Probing long-lived plasmonic-generated charges in TiO_2/Au by high-resolution x-ray absorption spectroscopy, *Angew. Chemie - Int. Ed.* 54 (2015). doi:10.1002/anie.201412030.
- [47] M.H. Rittmann-Frank, C.J. Milne, J. Rittmann, M. Reinhard, T.J. Penfold, M. Chergui, Mapping of the photoinduced electron traps in TiO_2 by picosecond x-ray absorption spectroscopy, *Angew. Chemie - Int. Ed.* 53 (2014) 5858–5862. doi:10.1002/anie.201310522.
- [48] Y. Obara, H. Ito, T. Ito, N. Kurahashi, S. Thürmer, H. Tanaka, T. Katayama, T. Togashi, S. Owada, Y. Yamamoto, S. Karashima, J. Nishitani, M. Yabashi, T. Suzuki, K. Misawa, Femtosecond time-resolved X-ray absorption spectroscopy of anatase TiO_2 nanoparticles using XFEL, *Struct. Dyn.* 4 (2017) 044033. doi:10.1063/1.4989862.
- [49] L. Tian, L. di Mario, V. Zannier, D. Catone, S. Colonna, P. O’Keeffe, S. Turchini, N. Zema, S. Rubini, F. Martelli, Ultrafast carrier dynamics, band-gap renormalization, and optical properties of ZnSe nanowires, *Phys. Rev. B.* 94 (2016) 165442. doi:10.1103/PhysRevB.94.165442.
- [50] I. Fratoddi, A. Cartoni, I. Venditti, D. Catone, P. O’Keeffe, A. Paladini, F. Toschi, S. Turchini, F. Sciubba, G. Testa, C. Battocchio, L. Carlini, R. Proietti Zaccaria, E. Magnano, I. Pis, L. Avaldi, Gold nanoparticles functionalized by rhodamine B isothiocyanate: A new tool to control plasmonic effects, *J. Colloid Interface Sci.* 513 (2018) 10–19. doi:10.1016/J.JCIS.2017.11.010.
- [51] B. Enright, D. Fitzmaurice, Spectroscopic Determination of Electron and Hole Effective Masses in a Nanocrystalline Semiconductor Film, *J. Phys. Chem.* 100 (1996) 1027–1035. doi:10.1021/jp951142w.
- [52] A. Molinari, A. Maldotti, R. Amadelli, Probing the Role of Surface Energetics of Electrons and their Accumulation in Photoreduction Processes on TiO_2 , *Chem. - A Eur. J.* 20 (2014) 7759–7765. doi:10.1002/chem.201402039.
- [53] B. Enright, C. Redmond, D. Fitzmaurice, Spectroscopic Determination of Flatband Potentials for Polycrystalline TiO_2 Electrodes in Mixed Solvent Systems, *J. Phys. Chem.* 98 (1994) 6195–6200. <https://pubs.acs.org/doi/pdf/10.1021/j100075a023> (accessed March 28, 2018).